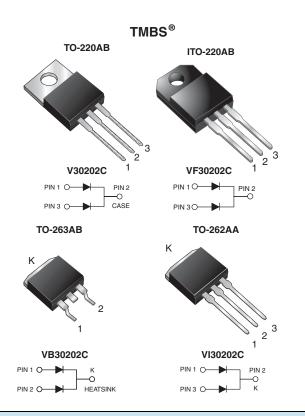


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Vishay General Semiconductor

Dual High Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.54 \text{ V}$ at $I_F = 5 \text{ A}$



PRIMARY CHARACTERISTICS						
I _{F(AV)}	2 x 15 A					
V_{RRM}	200 V					
I _{FSM}	260 A					
V_F at $I_F = 15$ A $(T_A = 125 ^{\circ}C)$	0.65 V					
T _J max.	175 °C					
Package	TO-220AB, ITO-220AB, TO-263AB, TO-262AA					
Diode variations	Common cathode					

FEATURES

- Trench MOS Schottky technology Gen 2
- · Low forward voltage drop, low power losses

rop, low power losses
on

RoHS

compliant
HALOGEN

FREE

- High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB, ITO-220AB, and TO-262AA package)
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, TO-263AB, and TO-262AA

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker testt

Polarity: as marked

Mounting Torque: 10 in-lbs max.

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)								
PARAMETER	SYMBOL	V30202C	VF30202C	VB30202C	VI30202C	UNIT		
Maximum repetitive peak reverse voltage	V _{RRM}	200				V		
Maximum average forward rectified current (fig. 1)per device		30				А		
per diode	I _{F(AV)}	15						
Maximum DC reverse voltage	V_{DC}	160				V		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I _{FSM}	260			Α			
Voltage rate of change (rated V _R)	dV/dt	10 000			V/µs			
Isolation voltage (ITO-220AB only) from terminal to heatsink, t = 1 min	V _{AC}	1500			V			
Operating junction and storage temperature range		-40 to +175			°C			



V30202C, VF30202C, VB30202C, VI30202C

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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)								
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT		
Instantaneous forward voltage per diode ⁽¹⁾	I _F = 5 A	T _A = 25 °C	V _F	0.69	-	. V		
	I _F = 10 A			0.75	-			
	I _F = 15 A			0.80	0.88			
	I _F = 5 A	T _A = 125 °C		0.54	-			
	I _F = 10 A			0.61	-			
	I _F = 15 A			0.65	0.72			
Reverse current per diode (2)	V 160 V	T _A = 25 °C	I _R	0.8	-	μA		
	V _R = 160 V	T _A = 125 °C		1.5	-	mA		
	V _D = 200 V	T _A = 25 °C		-	250	μA		
		T _A = 125 °C		4.0	14	mA		

Notes

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 5 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)								
PARAMETER		SYMBOL	V30202C	VF30202C	VB30202C	VI30202C	UNIT	
	per diode	$R_{ heta JC}$	1.8	4.0	1.	.8		
Typical thermal resistance	per device	$R_{ heta JC}$	1.0	2.8	1.0		°C/W	
	per device	R _{θJA} (1)(2)	52	60	5	2		

Notes

 $^{(1)}$ The heat generated must be less than the thermal conductivity from junction-to-ambient: $dP_D/dT_J < 1/R_{\theta JA}$

(2) Free air, without heatsink

ORDERING INFORMATION (Example)								
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE			
TO-220AB	V30202C-M3/4W	1.89	4W	50/tube	Tube			
ITO-220AB	VF30202C-M3/4W	1.75	4W	50/tube	Tube			
TO-263AB	VB30202C-M3/4W	1.38	4W	50/tube	Tube			
TO-263AB	VB30202C-M3/8W	1.38	8W	800/reel	Tape and reel			
TO-262AA	VI30202C-M3/4W	1.46	4W	50/tube	Tube			



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RATINGS AND CHARACTERISTICS CURVES ($T_A = 25~^{\circ}\text{C}$ unless otherwise noted)

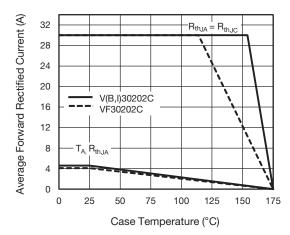


Fig. 1 - Maximum Forward Current Derating Curve

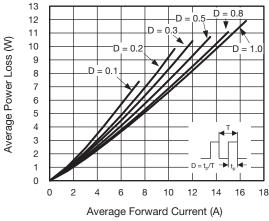


Fig. 2 - Forward Power Loss Characteristics Per Diode

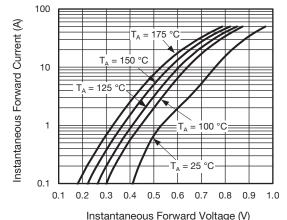


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

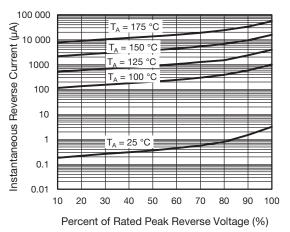


Fig. 4 - Typical Reverse Characteristics Per Diode

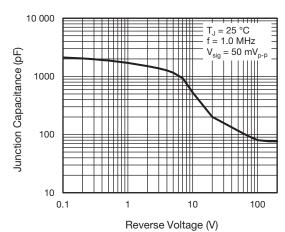


Fig. 5 - Typical Junction Capacitance Per Diode

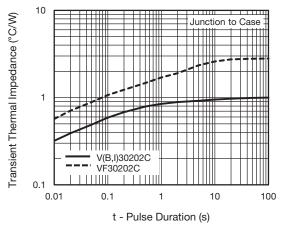


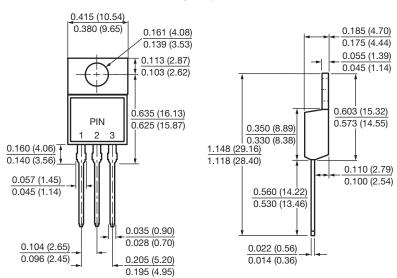
Fig. 6 - Typical Transient Thermal Impedance Per Device

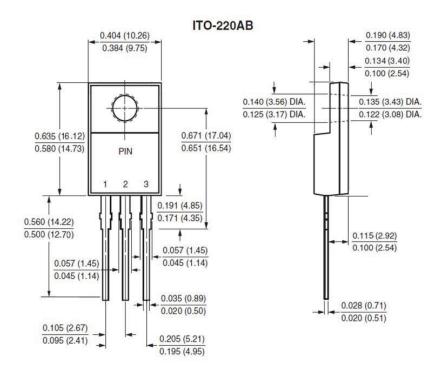


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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

TO-220AB

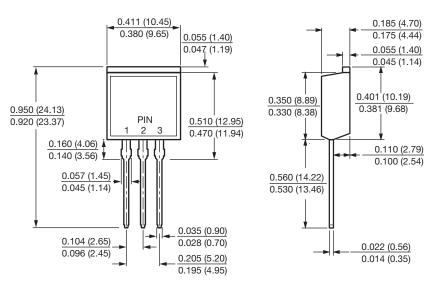




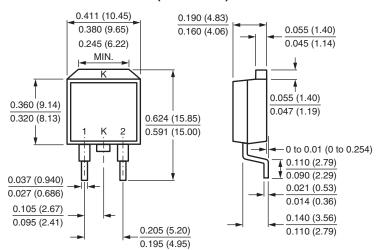


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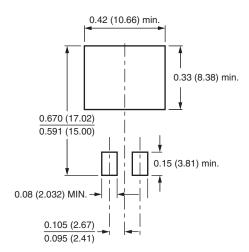
TO-262AA



D²PAK (TO-263AB)



Mounting Pad Layout



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